NPN Triple Diffused Planar Silicon Transistor



2SC4600

Switching Regulator Applications

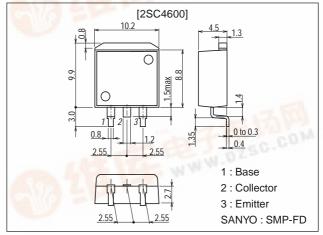
Features

- · Surface mount type device making the following possible.
- -Reduction in the number of manufacturing processes for 2SC4600-applied equipment.
- -High density surface mount applications.
- -Small size of 2SC4600-applied equipment.
- · High breakdown voltage, high reliability.
- · Fast switching speed.
- · Wide ASO.
- · Adoption of MBIT process.

Package Dimensions

unit:mm

2069C



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		800	V
Collector-to-Emitter Voltage	VCEO		500	V
Emitter-to-Base Voltage	V _{EBO}	140	7	V
Collector Current	IC		5	Α
Collector Current (Pulse)	I _{CP}	PW≤300μs, duty cycle≤10%	10	Α
Base Current	I _B	AND ARE INC. W	2	Α
Collector Dissipation	PC		1.65	W
		Tc=25°C	50	W
Junction Temperature	Tj	O Table	150	°C
Storage Temperature	Tstg	Com	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =500V, I _E =0			10	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0			10	μΑ
DC Current Gain	h _{FE} 1	V _{CE} =5V, I _C =0.6A	15*	M D	50*	17 (1
	h _{FF} 2	V _{CF} =5V, I _C =3A	8			

^{*:} For the h_{FE}1 of the 2SC4600, specify two ranks or more in principle.

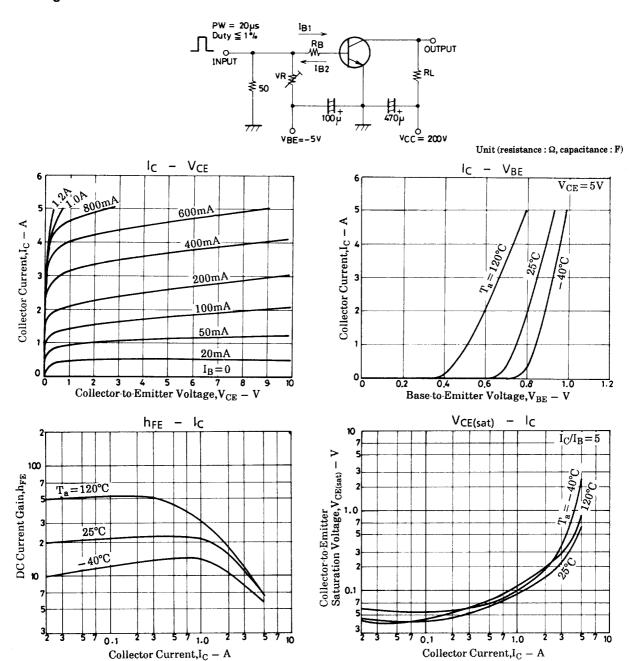
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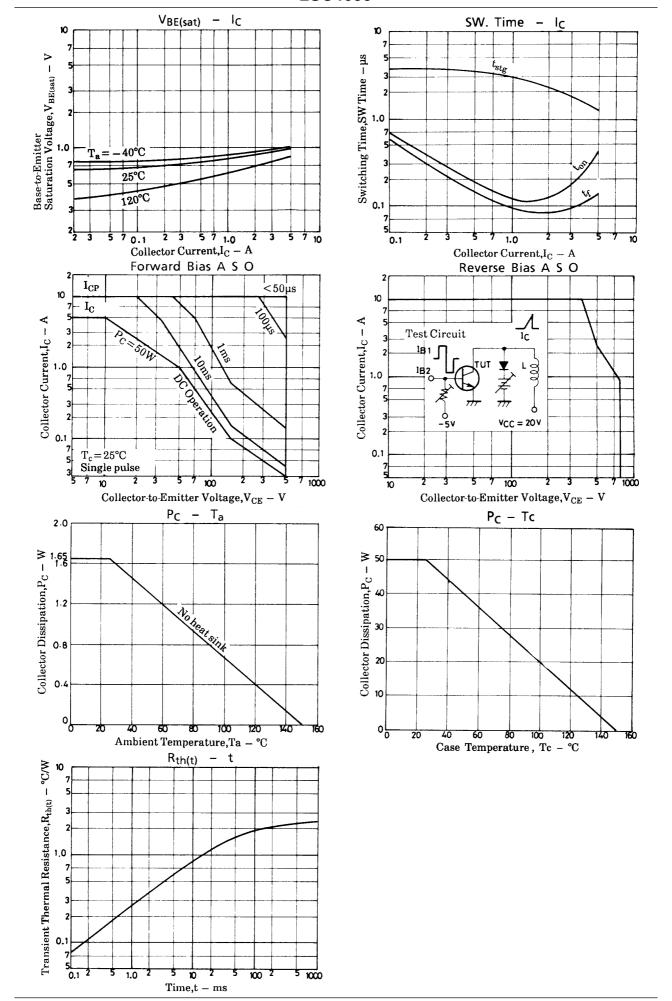
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Parameter	Symbol	Conditions	Ratings			Unit
Faianietei			min	typ	max	Offic
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.6A		18		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		80		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =3A, I _B =0.6A			1.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =3A, I _B =0.6A			1.5	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =1mA, I _E =0	800			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =5mA, R _{BE} =∞	500			٧
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	VCEO(sus)	I _C =5A, I _{B1} =1A, L=50μH	500			V
	V _{CEX(sus)}	I _C =2.5A, I _{B1} =-I _{B2} =1A, L=1mH, clamped	500			V
Turn-ON Time	ton	I _C =4A, I _{B1} =0.8A, I _{B2} =-1.6A, R _L =50Ω, V _{CC} =200V			0.5	μs
Storage Time	t _{stg}	I _C =4A, I _{B1} =0.8A, I _{B2} =-1.6A, R _L =50Ω, V _{CC} =200V			3.0	μs
Fall Time	t _f	I _C =4A, I _{B1} =0.8A, I _{B2} =-1.6A, R _L =50Ω, V _{CC} =200V			0.3	μs

Switching Time Test Circuit





2SC4600

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